MAINTENANCE MANUAL ORIONTM

UHF POWER AMPLIFIER UNITS

344A4573P1	20 WATT	403-440 MHz
344A4573P2	20 WATT	440-470 MHz
344A4573P3	40 WATT	403-440 MHz
344A4573P4	40 WATT	440-470 MHz
344A4573P5	35 WATT	470-512 MHz
344A4573P6	100 WATT	403-440 MHz
344A4573P7	100 WATT	440-470 MHz
344A4573P8	80 WATT	470-512 MHz

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DESCRIPTION

The Radio Frequency (**RF**) Power Amplifiers for the UHF **ORION**TM mobile radio are provided in three different frequency ranges and power levels designated as follows:

- 344A4573P1 (CAH-545EA) 403-440 MHz, 20 WATT used in low power applications
 344A4573P2 (CAH-545EB) - 440-470 MHz, 20 WATT used in low power applications
- 344A4573P3 (CAH-545AL) 403-440 MHz, 35/40 WATT used in mid power applications 344A4573P4 (CAH-545BL) - 440-470 MHz, 35/40 WATT used in mid power applications 344A4573P5 (CAH-545CL) - 470-512 MHz, 35/40 WATT used in mid power applications
- 344A4573P6 (CAH-545AH) 403-440 MHz, 80/100 WATT used in high power applications 344A4573P7 (CAH-545BH) - 440-470 MHz, 80/100 WATT used in high power applications 344A4573P8 (CAH-545CH) - 470-512 MHz, 80/100 WATT used in high power applications

The exciter for each of the three power amplifiers is located on Synthesizer/Receiver/Exciter board CMN-354-1. This exciter circuit provides approximately 500 milliwatt input to the PA (refer to Maintenance Manual LBI- 38905). The PA utilizes a single power amplifier module (HC1) as the driver unit. In the case of the 20 watt amplifier the power module is the only power amplifying unit (Refer to Figure 1). With the other two power levels the power module drives other power transistors to provide the power output required (Refer to Figures 2 and 3). Each power amplifier is provided with an antenna switch and limiter circuit to isolate the receive circuit from the transmit circuit, limiting the receiver input from being over driven due to large RF signals. Each power amplifier has a power detect circuit which controls an Automatic Power Control (APC) circuit to keep the power output constant. A low-pass filter is provided in the antenna circuit to reduce harmonic emissions. A keyed Tx 9V regulator is provided to power the APC circuits.

CIRCUIT ANALYSIS

20 WATT

The 20 Watt PA assembly uses one power module (HC1) to provide the output power.

Supply voltage for the power amplifier is connected from power leads on the System Interface Board to J3 (A+) and G (A-) on the PA Board. Diode CD7 is a surge protector to suppress pulses on the power leads. Diode CD8 will cause the fuse to blow if the polarity of the power leads is reversed.

The Exciter output is coupled through connector J151 on the Synthesizer/Receiver/Exciter Board to input connector J1 on the PA board. The 500 milliwatt RF input at J1 is coupled to power module HC1 through an attenuator pad consisting of resistors R1-R3. This pad attenuates the power to about 300 milliwatt and provides isolation between Exciter and PA. The power module (HC1) amplifies the 300 milliwatt input to 20 Watts.

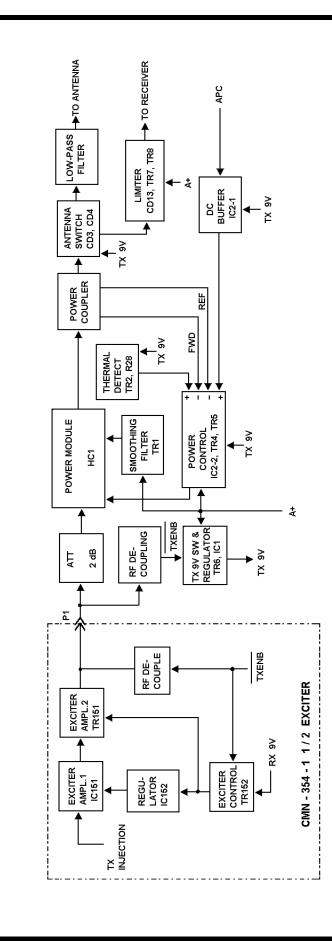
The power module consists of a three-stage RF amplifier (Refer to **IC DATA**). The first stage power supply voltage is supplied by the power control circuit. The second and third stage power supply voltage is supplied by **SMOOTHING FILTER** transistor TR1. The second and third stage RF amplifiers operate as class C.

The 20 Watts output of HC1 is coupled to the **ANTENNA** and **ANTENNA SWITCH & LIMITER** circuits through 50 ohm stripline Z1.

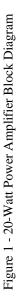
Antenna Switch & Limiter

The Antenna Switch circuit consists of capacitor C25 and inductor L9 and takes the place of a quarter-wave micro strip line. When **TX9V** output goes high, bias current flows through switching diodes CD3 and CD4. A low impedance now exists at the anode of CD4 and a high impedance exists at the node connection of C25 and L9. This isolates the transmitter power from the receiver. Diode CD3 is now an RF short and along with capacitor C12, couples the power to the lowpass filter and on to the antenna.

The limiter circuit consists of transistors TR7, TR8 and diode package CD13. While receiving, if the received signal level exceeds +10 dBm, the rectified currents of CD13 provide forward bias to TR7, TR8 and PIN diode CD4 proportional to the received signal level. This causes a quarter-wave circuit (lumped constants C25 and L9) to turn on when the received signal exceeds +10 dBm and protects the receiver from excessively high receive signal levels.







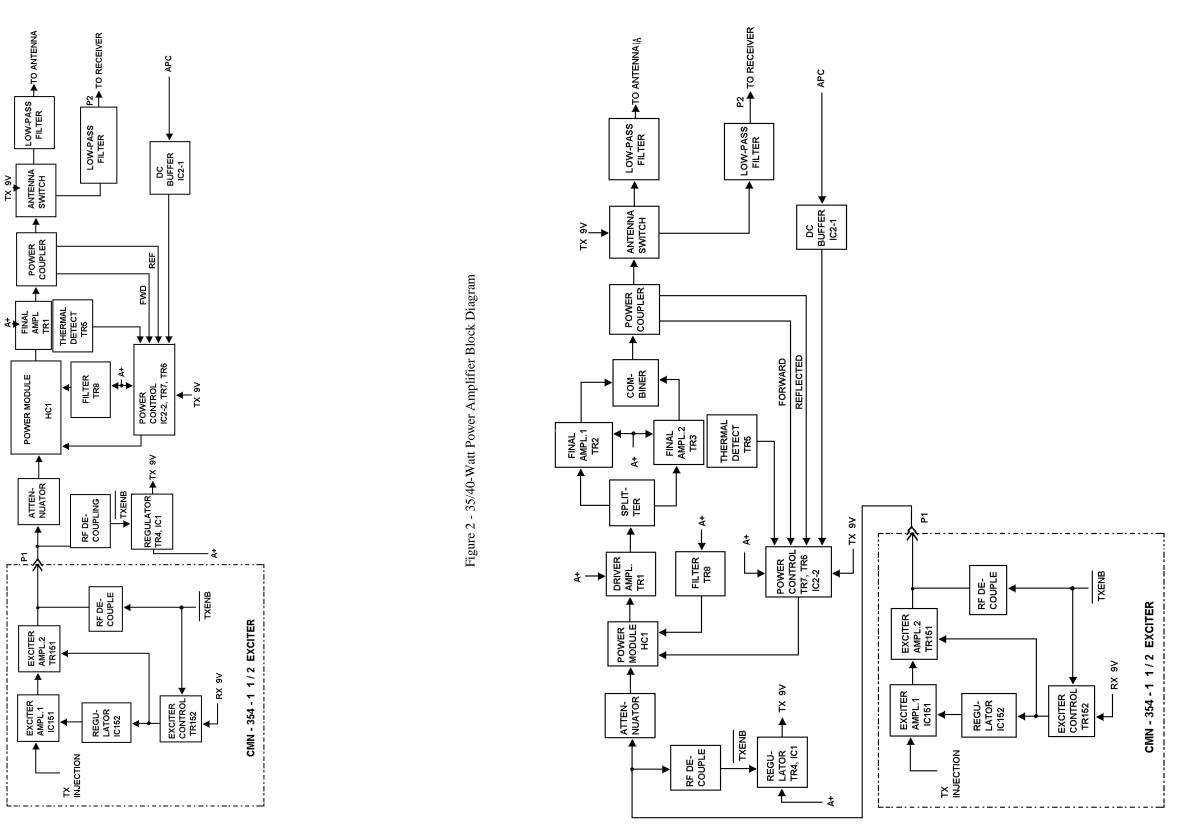


Figure 3 - 80/100 - Watt Power Amplifier Block Diagram

Tx 9V Switch

When the lead, located on the Synthesizer/Receiver/Exciter board, goes low, the DC voltage on J151 goes low. On the PA board, the DC voltage on J1 also goes low completing the circuit for diode CD9. With CD9 conducting TX 9V Switch transistor TR6 conducts applying A+(13.32 V) to the input of +9 Volt Regulator IC1. The regulated +9 volts applies bias to operational amplifier IC2, transistor TR2 and switching diodes CD3 and CD4.

Power Control

The Auto Power Control (APC) circuit protects the transmitter PA from damage due to:

a. excessive output power

b. excessive reflected power

or

c. excessive temperatury		c.	excessive	temperature
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The output power control circuit allows the RF output power to be set at rated power by the APC voltage from the Logic/IF/Audio Board. If the output power of the PA increases, the detected voltage and the input to operational amplifier IC2-2 increases. The output voltage of operational amplifier IC2-2 decreases. This causes **DC DRIVER** transistor TR5 to conduct less. This increases the base voltage on PNP DC PASS transistor TR4, causing it to conduct less. This results in less voltage being applied to the first amplifier stage in RF Power Module HC1, reducing the output power of the PA in proportion to the increases in output power detected by the circuit.

To protect the PA against badly mismatched loads, a reverse power detector circuit (VSWR) consisting of diode CD2, transistor TR5, operational amplifier IC2-2 and pass transistor TR4 detects reverse (reflected) power. When sufficient power is detected by CD2 to cause it to conduct, the voltage at the output of IC2-2 decreases, causing the Power Module to lower the output power, protecting the PA. The reverse power level is set by resistor R8 connected in series with diode CD2.

The PA is protected against temperature increases by a thermal detector circuit. This circuit consists of resistor R28, THERMAL DETECT transistor TR2, DC DRIVER transistor TR5 and DC AMPL operational amplifier IC2-2. As temperature increases, the resistance to ground through thermal detector resistor R28 increases. This causes IC2-2 to conduct less, causing a decrease in PA output until the temperature level is reduced. The temperature level is set by resistor R28. When the heatsink temperature rises above 90 C, the resistance of R28 increases and the power output is reduced.

35/40 WATT

The 35/40 Watt PA assembly uses one power module (HC1) and one RF power transistor (TR1) to provide the output power.

Supply voltage for the power amplifier is connected from power leads on the System Interface Board to J3 (A+) and G (A-) on the PA Board. Diode CD2 is a surge protector to suppress pulses on the power leads. (Diode CD1001 in the PA UNIT will cause a fuse to blow if the voltage polarity is reversed. Refer to the PA INTERCONNECTION DIAGRAM)

Test Points (TP) are the printed board terminals for measuring control voltage as follows:

- TP1 A+ (13.42V)
- TP2 Control Voltage (4.72V)
- TP3 Forward Power Detect (2.64V)
- TP4 Tx 9V (9.12V)
- TP5 APC Voltage on output of DC AMPL IC2-1 (2.64V)
- TP6 Voltage to HC1, pins 3 &4 (12.5V)
- TP7 APC Voltage (3.5V)

The Exciter output is coupled through connector J151 on the Synthesizer/Receiver/Exciter Board to input Jack P1 on the PA board. The 500 milliwatt RF input at P1 is coupled to power module HC1 through an attenuator pad consisting of resistors R1-R4. This pad attenuates the 500 milliwatt to about 300 milliwatt and provides isolation between Exciter and PA. The power module (HC1) amplifies the 300 milliwatt input to 13 Watts.

The power module consists of a three-stage RF amplifier (Refer to IC DATA). The first stage power supply voltage is supplied by the power control circuit. The second and third stage power supply voltage is supplied by SMOOTHING FILTER transistor TR8. The second and third RF amplifiers operate as class C.

The 13 Watts output of HC1 is coupled to **POWER AMPL** transistor TR1 through impedance matching components consisting of capacitors C7, C9, C10 and inductor L2 through coupling capacitor C8. Transistor TR1 amplifies the 13 Watt level to 40 Watts. The output of TR1 is coupled to the ANTENNA and ANTENNA SWITCH through impedance matching components consisting of capacitors C11-C13, inductor L6 and impedance matching network Z2 through coupling capacitor C14 and 50 ohm stripline Z7.

Antenna Switch

The Antenna Switch circuit consists of capacitor C64 and inductor L23 and takes the place of a quarter-wave micro strip line. When **TX9V** output goes high, bias current flows through switching diodes CD5, CD7 and CD9. A low impedance now exists at the anode of CD7 and a high impedance exists at the connection of C64 and L23. This isolates the transmitter power from the receiver. Diode CD5 is now an RF short and along with capacitor C55 couples the power to the lowpass filter and on to the antenna.

Tx 9V Switch

When the **TX ENB** lead goes low, TX 9V switch transistor TR4 conducts applying A+ (13.32 V) to the input of +9 Volt Regulator IC1. The regulated +9 volts (TX 9V) applies bias to operational amplifier IC2, transistor TR5 and switching diodes CD5, CD7 and CD9.

Power Control

The Auto Power Control (APC) circuit protects the transmitter PA from damage due to: a. excessive output power b. excessive reflected power or c. excessive temperature

The output power control circuit allows the RF output power to be set at rated power by the APC voltage from the Logic/IF/Audio Board. If the output power of the PA increases, the detected voltage and the input of operational amplifier IC2-2 increases. The output voltage of IC2-2 decreases. This causes DC DRIVER transistor TR6 to conduct less. This increases the base voltage on PNP DC PASS transistor TR7, causing it to conduct less. This results in less voltage being applied to the first amplifier stage in driver module (HC1), reducing the output power of the PA in proportion to the increases in output power detected by the circuit.

To protect the PA against badly mismatched loads, a reverse power detector circuit (VSWR) consisting of diode CD4, transistor TR6, operational amplifier IC2-2 and pass transistor TR7 detects reverse (reflected) power. When sufficient power is detected by CD4 to cause it to conduct, the voltage at the output of IC2-2 decreases, causing the driver module to lower the output power, protecting the PA. The re-

LBI-39034C

verse power level is set by resistor R15 connected in series with diode CD4.

The PA is protected against temperature increases by a thermal detector circuit. This circuit consists of resistor R49. transistors TR5, TR6, TR7 and operational amplifier IC2-2. As temperature increases, the resistance to ground through thermal detector resistor R49 increases. This causes IC2-2 to conduct less, causing a decrease in PA output until the temperature level is reduced. The temperature level is set by resistor R49. When the heatsink temperature rises above 90 C, the resistance of R49 increases and the power output is reduced.

80/100 WATT

The 80/100 Watt PA assembly uses one power module (HC1) and three RF power transistors (TR1, TR2 and TR3) to provide the output power.

Supply voltage for the power amplifier is connected from power leads on the System Interface Board to J3 (A+) and G (A-) on the PA Board. Capacitors C73 and C95 prevent RF from getting on the power leads. Diode CD1 causes a fuse to blow if the polarity of the power leads is reversed. Diode CD2 is a surge protector to suppress pulses on the power leads.

Test Points (TP) are the printed board terminals for measuring control voltage as follows:

- TP1 A+ (13.32V)
- TP2 Control Voltage (4.27V)
- TP3 Forward Power Detect (3.2V)
- TP4 Tx 9V (9.2V)
- TP5 APC Voltage on output of DC AMPL IC2-1 (2.66V)
- TP6 Voltage to HC1, pins 3 &4 (12.8V)
- TP7 APC Voltage (3.5V)

The exciter output is coupled through connector J102 on the Synthesizer/Receiver/Exciter Board to input Jack P1 on the PA board. The 500 milliwatt RF input at P1 is coupled to power module HC1 through an attenuator pad consisting of resistors R1 through R4. This pad attenuates the 500 milliwatt input to 300 milliwatt and provides isolation between the Exciter and PA. POWER MODULE HC1 amplifies the 300 milliwatt input to 12 Watts. The power module (HC1) consists of a three stage RF amplifier. The first stage of the module is controlled by the voltage from the power control circuit. The amplifier consist of a Class C driver amplifier and two Class C common-emitter amplifiers. The 12 watt

403-512 MHz. 20-WATT POWER MODULE HC1

403-512 MHz. 35/40 -WATT POWER MODULE HC1

output is coupled to DRIVER AMPL transistor TR1 through impedance matching components consisting of capacitors C7, C9 C10, inductors L2 through L4 and coupling capacitor C8. The output of TR1 is coupled to the power **SPLITTER** through the impedance matching components consisting of capacitors C11 through C13, C15, C96, C97, inductor L6 and impedance matching network Z1 through coupling capacitor C14. Transistor TR1 amplifies the 12 watt input level to 40 watts. The power splitter consists of capacitors C18, C27, C36 and Inductors L7 and L11. Resistor R5 absorbs any unbalance in the drive to POWER AMPL-1. AMPL-2 transistors TR2 and TR3. These power amplifier stages consist of two identical paralleled Class C power amplifiers. The output of the power splitter is coupled to transistors TR2 and TR3 through coupling capacitors C19 and C28 and the impedance matching components consisting of capacitors C20, C21, C29 and C30. The output of TR2 and TR3 is coupled to the power combiner through impedance matching components consisting of capacitors C22-C25, C31-C34 and impedance matching networks Z2 and Z3. The power COMBINER consists of capacitors C26, C35, C40, C41 and inductors L10, L14 and L15, Resistor R8 absorbs the difference in the output power of TR2 and TR3. Transistors TR2 and TR3 each amplify the input level from 20 watts to about one-half (1/2) of the rated output power. The output of the combiner is coupled to the ANTENNA **SWITCH** through 50 ohm stripline Z7.

Antenna Switch

The antenna switch circuit consists of capacitor C64 and inductor L23 and takes the place of a quarter-wave micro strip line. When **TX9V** output goes high, bias current flows through switching diodes CD6 through CD9. A low impedance now exists at the anode of CD7 and CD8 and high impedance exists at the connection of C64 and L23. This isolates the transmitter power from the receiver. Diode CD6 is now an RF short and along with capacitor C55 couples the power to the lowpass filter and on to the antenna.

Tx 9V Switch

When the **TX ENB** lead goes low, **TX 9V** switch transistor TR4 conducts applying A+ (13.32 V) to the input of +9 Volt Regulator IC1. The regulated +9 volts (**TX 9V**) applies bias to operational amplifier IC2, transistor TR5 and switching diodes CD6 through CD9.

Power Control

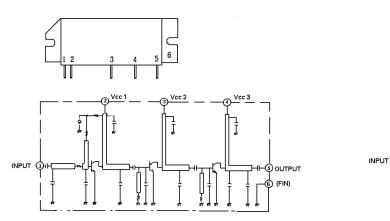
The Automatic Power Control (APC) circuit protects the transmitter PA from damage due to:

- a. excessive output power
- b. excessive reflected power
- or
- c. excessive temperature

The output power control circuit allows the RF output power to be set at rated power by the APC voltage from the LOGIC/IF/AUDIO Board. If the output power of the PA increases, the detected voltage and the input of operational amplifier IC2-2 increases. The output voltage of operational amplifier IC2-2 decreases. This causes transistor TR6 to conduct less. This increases the base voltage on PNP pass transistor TR7, causing it to conduct less. This results in less voltage being applied to the first amplifier stage in driver module (HC1), reducing the output power of the exciter/ PA in proportion to the increases in output power detected by the circuit.

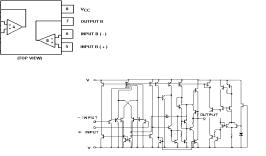
To protect the PA against badly mismatched loads, a reverse power detector circuit (VSWR) consisting of diode CD4, transistor TR6, operational amplifier IC2-2 and pass transistor TR7 detect reverse (reflected) power. When sufficient power is detected by CD4 to cause it to conduct, the voltage at the output of IC2-2 decreases, causing the driver module to lower the output power, protecting the PA. The reverse power level is set by resistor R15 connected in series with diode CD4.

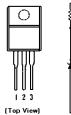
The PA is protected against temperature increases by a thermal detector circuit. This circuit consists of resistor R49, transistors TR5, TR6, TR7 and operational amplifier IC2-2. As temperature increases, the resistance to ground through thermal detector resistor R49 increases. This causes IC2-2 to conduct less, causing a decrease in PA output until the temperature level is reduced. The temperature level is set by resistor R49. When the heatsink temperature rises above 90 C, the resistance of R49 increases and the power output is reduced.

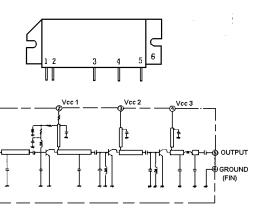


9 VOLT REGULATOR IC1

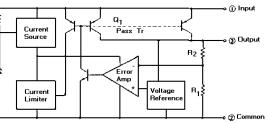








OPERATIONAL AMPLIFIER IC2



PA UNIT (EUROPEAN MODEL) 344A4573P1/JHM-471AE, 344A4573P2/JHM-471PBE

SYMBOL	PART NO.	DESCRIPTION
A1	NOTE: Parts listed are for reference	PA CIRCUIT CAH-545EA (Used in 344A4573P1).
A1	only. Refer to Service Section for	PA CIRCUIT CAH-545EB (Used in 344A4573P2).
A2	serviceable parts.	INTERFACE CMH-1231E.
		CAPACITORS
C1001 and C1002		Ceramic: 1000 pF +50%, -20% 50 VDCW temp coef ±15%.
		CONNECTORS
J1001		H-6JALD00005.
TB1001		2 ALB-01A.
		WIRE
W1001		250V-HV-19/0.18-(2)
		COAXIAL CABLES
ZC1002		H-6JJLD25150.
ZC1003		H-6JJLD027076.
ZC1004		H-6ZCLD41060.

PA UNIT (USA MODEL)

344A573P3/JHM-471PAL 344A573P4/JHM-471PBL

344A4573P5/JHM-471PCL 344A4573P6/JHM-471PAH 344A4573P7/JHM-471PBH 344A4573P8/JHM-471PCH

SYMBOL	PART NO.	DESCRIPTION
A1001	NOTE: Parts listed are for reference	PA CIRCUIT CAH-545AL (Used in 344A4573P3).
A1001	only. Refer to Service Section for	CIRCUIT CAH-545BL (Used in 344A4573P4).
A1001	serviceable parts.	PA CIRCUIT CAH-545CL (Used in 344A4573P5).
A1001		PA CIRCUIT CAH-545AH (Used in 344A4573P6).
A1001		PA CIRCUIT CAH-545BH (Used in 344A4573P7).
A1001		PA CIRCUIT CAH-545CH (Used in 344A4573P8).
A1002		INTERFACE (Used in 344A4573P3,P4,P5).
A1002		INTERFACE (Used in 344A4573P6,P7,P8).
		CAPACITORS
C1001		Ceramic: 1000 pF +200%,-0%, 50 VDCW temp coef +20%,-55%.
C1002		Ceramic: 1000 pF +200%,-0%, 50 VDCW temp coef +20%,-55% (Used in P6,P7,P8).
C1004		Ceramic: 1000pF +50-20% 50 VDCW.
		DIODE
CD1001		Silicon fwd current 3A, 200 PIV ;sim to MOTOROLA MR751 (Used in 344A4573P3,P4,P5).
		JACKS
J1001		Connector: ALB05.
J1002		CCT9402-0501R.
		TERMINALS
TB1001		ALB-01A.
		COAXIAL CABLES
ZC1002		H-6ZCLD41060.
ZC1003		H-6ZCLD40111 (Used in 344A4573P6,P7,P8).
ZC1003		H-6ZCLD40009 (Used in 344A4573P3,P4,P5).
COMPONENT	S, ADDED, DELETED OR	CHANGED BY PRODUCTION CHANGES

POWER AMPLIFIER CAH-545E - 20 WATT		SYMBOL	PART NO.	DESCRIPTION	
		(Used in 344A4573P1) (Used in 344A4573P2)	C39 and C40		Ceramic: 100 pF \pm 5% 50 VDCW, temp coef 0 \pm 30 PPM.
SYMBOL	PART NO.	DESCRIPTION	C43		Ceramic: 6 pF \pm 0.5 pF 500 VDCW, temp coef 0 \pm 60 PPM.
		CAPACITORS	C44		Ceramic: 4 pF ±0.25 pF% 50 VDCW, temp coef 0±30PPM.
C1 and C2	NOTE: Parts listed are for reference only. Refer to	Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM.	C60 thru		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60PPM.
C3	Service Section for serviceable parts.	Electrolytic: 33 μ F ±20% 25 VDCW, temp coef ±20%.	C62		DIODES
C4	sei viceable parts.	Film: 0.1 µF ±10% 50 VDCW, temp coef ±15%.	CD1 and		Silicon: sim to PANASONIC MA741-TX.
C5		Ceramic: 4.7 pF $\pm 10\%$ 50 VDCW, temp coef $\pm 10\%.$	CD2 CD3		PIN DIODE: sim to MITSUBISHI M1809-
C7		Ceramic: 100 pF \pm 5% 50 VDCW, temp coef 0 \pm 30 PPM.	and CD4 CD7		T11. VARISTOR: sim to PANASONIC ERZ-
C8		Ceramic: 7 pF \pm 0.5pF 50 VDCW, temp coef 0 \pm 30PPM. (Used in EA).	-		CF2MK220.
C8		Ceramic: 6 pF \pm 0.5pF 50 VDCW, temp coef 0 \pm 30PPM. (Used in EB).	CD8 CD9		Silicon: sim to MOTOROLA MR751. Silicon: fast recovery (2 diodes in cathode common): sim to TOSHIBA
C11		Ceramic: 7 pF ± 0.5 pF 50 VDCW, temp coef 0 ± 30 PPM. (Used in EA).	CD13		ISS184 Silicon: fast recovery : sim to TOSHIBA
C11		Ceramic: 6 pF \pm 0.5pF 50 VDCW, temp coef 0 \pm 30PPM. (Used in EB).	0013		ISS226.
C12		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60 PPM.			INTEGRATED CIRCUITS
C13 and C14		Ceramic: 3 pF ±0.25pF 500 VDCW, temp coef 0±120 PPM.	HC1		RF Power Amplifier: sim to MITSUBISHI M57788L-38 (Used in EA).
C14 C15		Ceramic: 2 pF ±0.25 PF 500 VDCW, temp coef 0±250 PPM.	HC1		RF Power Amplifier: sim to MITSUBISHI M57788H-38 (Used in EB).
C16		Ceramic: 3 pF ±0.25pF 500 VDCW, temp coef 0±120 PPM.	IC1		Linear: Positive Voltage Regulator; sim to PANASONIC AN6541.
C17		Ceramic: 5 pF ±0.25pF 500 VDCW, temp coef 0±60 PPM.	IC2		Linear: Dual OP Amp: sim to NEW JRC- NJM 3404 AM-T1.
C19		Ceramic: 6 pF \pm 0.5pF 500 VDCW, temp coef 0 \pm 60PPM.			CONNECTORS
C20		Ceramic: 2 pF \pm 0.25 PF 500 VDCW, temp coef 0 \pm 250 PPM.	J1 and		Connector.
C21		Electrolytic: 220 μF ±20% 25 VDCW, temp coef ±20%.	J2 J3		Connector.
C22 thru		Ceramic: 100 pF \pm 5% 50 VDCW, temp coef 0 \pm 30 PPM.	J4		Connector.
C24 C25		Ceramic: 4 pF ±0.25 pF 500 VDCW, temp	L1		Coil: 0.22 μH.
C26		coef 0±60 PPM. Ceramic: 4 pF ±0.25 pF 50 VDCW, temp	L2 L3		Coil: RF 0.22 μH. Coil: 19 nH.
C27		coef 0±30 PPM. Ceramic: 2 pF ±0.25 pF 50 VDCW, temp	and L4		Con. 19111.
C28		coef 0±30 PPM. Ceramic: 100 pF ±5% 50 VDCW, temp coef	L5 thru		RF Coil: AIRWOUND.
C30		0±30 PPM. Tantalum: 4.7 μF ±20% 25 VDCW.	L8 L9		Coil: RF 19 nH.
C31		Electrolytic: 10 μ F ±20% 25 VDCW, temp coef ±20%.	and L10		
C32		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30PPM.	L9 and L10		Coil: RF 19 nH.
C34		Electrolytic: 10 μF ±20% 25 VDCW, temp coef ±20%.	L11		Coil: RF 0.22 µH.
C35		Ceramic: 100 pF \pm 5% 50 VDCW, temp coef 0 \pm 30 PPM.	R1		RESISTORS Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
C36 C37		Tantalum: 1 uF ±20% 16 VDCW.	R2		Metal film: 12 ohms ±5%, 200 VDCW,
C37		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM. Ceramic: 0.1 µF +80%,-20% 25 VDCW,	R3		1/4W. Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
		temp coef +30%,-80%.			1/ 1 U VV.

PARTS LIST

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SYMBOL	PART NO.	DESCRIPTION
R4		Metal film: 22 ohms ±5%, 200 VDCW,
and		1/2W.
R5		Matal film: 100 abma 15% 250 MDCM
R6		Metal film: 100 ohms ±5%, 250 VDCW, 1W.
R8		Metal film: 100 ohms ±5%, 100 VDCW, 1/10W.
R9		Metal film: 47 ohms ±5%, 100 VDCW,
and R10		1/10W.
R11		Metal film: 47K ohms ±5%, 200 VDCW, 1/8W.
R14		Metal film: 27K ohms ±5%, 100 VDCW, 1/10W.
R15		Metal film: 2.7K ohms ±5%, 100 VDCW, 1/10W.
R16		Metal film: 390 ohms ±5%, 200 VDCW, 1/4W.
R17		Metal film: 470 ohms ±5%, 200 VDCW, 1/4W.
R18		Metal film: 1K ohms ±5%, 100 VDCW, 1/10W.
R19 thru		Metal film: 2.2K ohms ±5%, 200 VDCW, 1/10W.
R21		
R22		Metal film: 100k ohms ±5%, 100 VDCW, 1/10W.
R23		Metal film: 3.3K ohms ±5%, 100 VDCW, 1/10W.
R24		Metal film: 4.7k ohms ±5%, 100 VDCW, 1/10W.
R25		Metal film: 2.2K ohms ±5%, 100 VDCW, 1/10W.
R26		Metal film: 47K ohms ±5%, 100 VDCW, 1/10W.
R27		Metal film: 1K ohms ±5%, 100 VDCW, 1/10W.
R28		Posistor: sim to MURATA PTH9M04BE222TS2F333.
R35		Metal film: 100 ohms ±5%, 250 VDCW, 1W.
R36		Metal film: 10K ohms ±5%, 100 VDCW, 1/10W.
RV1		Variable: 10K ohms TRANSISTORS
TR1		Silicon, NPN: sim to PANASONIC 2SD1445A.
TR2		Silicon, NPN: sim to NEC 2SD596-T1B DV3.
TR4		Silicon, PNP: sim to PANASONIC 2SB953A.
TR5		Silicon, NPN: sim to NEC 2SD596-T1B DV3.
TR6		Silicon, PNP: sim to NEC 2SB624-T1B BV3.
TR7		Silicon, NPN: sim to NEC 2SD596-T1B DV3.
TR8		Silicon, PNP: sim to NEC 2SB624-T1B BV3.

(Continued)

UHF POWER AMPLIFIER CAH-545L - 35/40 WATT CAH-545H - 80/100 WATT CAH-545AL (Used in 344A4573P3), CAH-545BL (Used in 344A4573P4) CAH-545CL (Used in 344A4573P5), CAH-545AH (Used in 344A4573P6) CAH-545BH (Used in 344A4573P7), CAN-545CH (Used in 344A4573P8)

				C17
SYMBOL	PART NO.	DESCRIPTION		C18
		CAPACITORS		C18
C1 and C2	NOTE: Parts listed are for reference only. Refer to	Ceramic: 100 pF \pm 5% 50 VDCW, temp coef 0 \pm 30 PPM.		C18
C3	Service Section for serviceable parts.	Electrolytic: 33 μF ±20% 25 VDCW, temp coef ±20%.		C19
C5		Ceramic: 0.01 μF ±10% 50 VDCW, temp coef 0±10%.		C20
C6		Ceramic: 0.1 µF +80%,-20% 50 VDCW, temp coef +30%,-80%.		C20
C7		Ceramic: 12 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in AL,BL,AH,).		C20
C7		Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in CL,BH,CH).		C21
C7		Ceramic: 8 pF \pm 0.5pF, 500 VDCW, temp coef 0 \pm 60PPM (Used in CL).		C21
C8		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60PPM.		C21
C9		Ceramic: 56 pF \pm 5% 500 VDCW, temp coef 0 \pm 60PPM (Used in AL, AH).		C22
C9		Ceramic: 47 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in BL,CL,BH,CH).		C22
C10		Ceramic: 56 pF \pm 5% 500 VDCW, temp coef 0 \pm 60PPM (Used in AL,AH).		C22
C10		Ceramic: 43 pF \pm 5% 500 VDCW, temp coef 0 \pm 60PPM (Used in BH).		C23
C10		Ceramic: 36 pF \pm 5% 500 VDCW, temp coef 0 \pm 60PPM (Used in CL,CH).		C23
C10		Ceramic: 47 pF \pm 5% 500 VDCW, temp coef 0 \pm 60PPM (Used in BL).		C24
C11		Metal mica: 56 pF \pm 5% 100 VDCW, (Used in AH, BH).		C24
C11		Metal mica: 36 pF \pm 5% 100 VDCW, (Used in AL).		C24
C11		Metal mica: 33 pF \pm 5% 100 VDCW, (Used in BL,CL,CH).		C25
C12		Metal mica: 39 pF \pm 5% 100 VDCW, (Used in AH).		C26
C12		Metal mica: 47 pF \pm 5% 100 VDCW, (Used in BL,CL).		C26
C12		Metal mica: 33 pF \pm 5% 100 VDCW, (Used in BH,CH).		C27
C12		Metal mica: 51 pF \pm 5% 100 VDCW (Used in AL).		C27
C13		Mica: 30 pF \pm 5% 500 VDCW (Used in AL,AH).		C27
C13		Mica: 24 pF ±5% 500 VDCW (Used in CL).		C28
C13 C13		Mica: 30 pF ±5% 500 VDCW (Used in AH). Mica: 27 pF ±5% 500 VDCW (Used in BL).		C29
C13		Mica: 27 pr ±5% 300 VDCW (Used in BL). Mica: 24 pF ±5% 100 VDCW (Used in BH).		
C14		Mica: 90 pF ±5% 500 VDCW (Used in		C29
C14		AL,BL,CL). Ceramic: 100 pF ±5% 500 VDCW, temp		C29
C15		coef 0±60PPM (Used in AH, BH,CH). Ceramic: 3 pF ±0.25pF 500 VDCW, temp		C30
C15		coef 0±60PPM (Used in AH). Ceramic: 5 pF ±0.25pF 500 VDCW, temp		C30
C15		coef 0 \pm 60PPM (Used in AH,BH). Ceramic: 4 pF \pm 0.25 pF 500 VDCW, temp coef 0 \pm 60PPM (Used in CH).		C30
				C31
		OR CHANGED BY PRODUCTION CHANGES	-	

SYMBOL	PART NO.	DESCRIPTION
C16		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60PPM.
C17		Electrolytic: 22 μ F ±10% 40 VDCW, (Used in AH, BH,CH).
C18		Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in AH).
C18		Ceramic: 9 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in BH).
C18		Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in CH).
C19		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in AH,BH,CH).
C20		Mica: 56 pF ±5% 500 VDCW (Used in AH).
C20		, Mica: 47 pF ±5% 500 VDCW (Used in BH).
C20		Mica: 36 pF ±5% 500 VDCW (Used in CH).
C21		Mica: 47 pF ±5% 500 VDCW (Used in AH).
C21		Mica: 39 pF ±5% 500 VDCW (Used in BH).
C21		Mica: 36 pF ±5% 500 VDCW (Used in CH).
C22		Metal mica: 39 pF ±5% 100 VDCW (Used in AH).
C22		Metal mica: 36 pF ±5% 100 VDCW (Used in BH,CH).
C22		Metal mica: 33 pF ±5% 100 VDCW (Used in CH).
C23		Metal mica: 56 pF ±5% 100 VDCW (Used in AH,BH).
C23		Metal mica: 47 pF ±5% 100 VDCW (Used in BH).
C24		Metal mica: 30 pF ±5% 100 VDCW (Used in AH).
C24		Metal mica: 24 pF ±5% 100 VDCW (Used in BH).
C24		Metal mica: 18 pF ±5% 100 VDCW (Used in CH).
C25		Mica: 90 pF ±5% 500 VDCW (Used in AH,BH,CH).
C26		Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in AH,BH.
C26		Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in CH).
C27		Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in AH).
C27		Ceramic: 9 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in BH).
C27		Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM. (Used in CH).
C28		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60PPM. (Used in AH,BH,CH).
C29		Mica: 47 pF ±5% 500 VDCW. (Used in AH).
C29		Mica: 39 pF ±5% 500 VDCW (Used in BH).
C29		Mica: 36 pF ±5% 500 VDCW (Used in CH).
C30		Mica: 56 pF ±5% 500 VDCW (Used in AH).
C30		Mica: 47 pF ±5% 500 VDCW (Used in BH).
C30		Mica: 36 pF ±5% 500 VDCW (Used in CH).
C31		Metal mica: 56 pF ±5% 100 VDCW (Used in AH).

PARTS LIST

SYMBOL	PART NO.	DESCRIPTION	SYMBOL
C31		Metal mica: 47 pF \pm 5% 100 VDCW (Used in BH,CH).	C55
C32		Metal mica: 39 pF ±5% 100 VDCW (Used in AH).	C56
C32		Metal mica: 36 pF ±5% 100 VDCW (Used in BH,CH).	C56
C32		Metal mica: 33 pF ±5% 500 VDCW (Used in CH).	C57
C33		Metal mica: 30 pF ±5% 100 VDCW (Used in AH).	C57
C33		Metal mica: 27 pF ±5% 100 VDCW (Used in BH).	C57
C33		Metal mica: 24 pF ±5% 100 VDCW (Used in CH).	C58
C34		Mica: 90 pF ±5% 500 VDCW (Used in AH,BH,CH).	C58
C35		Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM. (Used in AH,BH).	C59
C35		Ceramic: 8 pF \pm 0.5pF 500 VDCW, temp coef 0 \pm 60PPM (Used in CH).	C59
C36		Ceramic: 6 pF \pm 0.5pF 500 VDCW, temp coef 0 \pm 60PPM (Used in AH,BH,CH).	C59
C37		Electrolytic: 22 μF $\pm 10\%$ 40 VDCW (Used in AH,BH,CH).	C59
C38		Ceramic: 0.1 µF +80%,-20% 50 VDCW, temp coef +30%, -80% (Used in AH,BH,CH).	C60
C39		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in AH,BH,CH).	C60
C40		Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in AH,BH,CH).	C60
C41		Mica: 8 pF \pm 0.5pF 500 VDCW (Used in AH, BH).	C60
C41		Mica: 6 pF \pm 0.5pF 50 VDCW, (Used in CH).	C61
C41		Ceramic: 12 pF \pm 5% 500 VDCW, temp coef 0 \pm 60PPM (Used in AL).	C61
C41		Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in BL,CL).	C62
C44		Ceramic: 6 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in AH).	C62
C44		Ceramic: 5 pF ±0.25pF 50 VDCW, temp coef 0±30PPM. (Used in BH,CH).	C63
C44		Ceramic: 7 pF ±0.5pF 50 VDCW, temp coef 0±30PPM. (Used in AL,BL,CL).	C63
C45		Ceramic: 6 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in AH).	C64
C45		Ceramic: 5 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in BH,CH).	C64
C47 and		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM.	C64
C48 C49		Ceramic: 8 pF \pm 0.5 pF, 50 VDCW, temp coef	C64
C49		0±30 PPM. (Used in AH). Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef	C64
C49		0±30 PPM. (Used in BH). Ceramic: 2 pF ±0.25 pF, 50 VDCW, temp	C64
C50		coef 0±30 PPM (Used in CL). Ceramic: 4 pF ±0.25 pF, 50 VDCW, temp	C65
C50		coef 0±30 PPM (Used in CH). Ceramic: 6 pF ±0.5 pF, 50 VDCW, temp coef	C65
C51		0±30 PPM (Used in AL,BL,CL). Ceramic: 100 pF ±5%, 50 VDCW, temp coef	C65
C52		0±30 PPM. Ceramic: 1000 pF ±10% 50 VDCW, temp	C66
C53		coef $0\pm15\% \pm15\%$ (Used in AH,BH,CH). Ceramic: 100 pF $\pm5\%$ 50 VDCW, temp coef	C66
C54		0 \pm 30PPM. Ceramic: 100 pF \pm 5% 50 VDCW, temp coef	C66
004		0 ± 30 PPM.	

*COMPONENTS, ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

Ceramic: 100 pF $\pm 5\%$ 500 VDCW, t 0 ± 60 PPM. Ceramic: 3 pF ± 0.25 pF 500 VDCW coef 0 ± 120 PPM (Used in AH,BH). Ceramic: 4 pF ± 0.25 pF 500 VDCW, 0 ± 60 PPM (Used in CH). Ceramic: 5 pF ± 0.5 pF 500 VDCW, 0 ± 60 PPM (Used in CH). Ceramic: 7 pF ± 0.5 pF 500 VDCW, 0 ± 60 PPM (Used in CH). Ceramic: 3 pF ± 0.25 pF 500 VDCW, 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 3 pF ± 0.25 pF 500 VDCW, 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 2 pF ± 0.25 pF 500 VDCW, coef 0 ± 120 PPM (Used in AL,AH,B Ceramic: 2 pF ± 0.25 pF 500 VDCW, coef 0 ± 250 PPM (Used in AL,AH,B Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 250 PPM (Used in AH,BH,CL,CH). Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 250 PPM (Used in AH,BH,C). Ceramic: 5 pF ± 0.25 pF 500 VDCW, coef 0 ± 250 PPM (Used in AL,BL,CL,CH). Ceramic: 4 pF ± 0.25 pF 500 VDCW, coef 0 ± 200 PPM (Used in AL,BL). Ceramic: 4 pF ± 0.25 pF 500 VDCW coef 0 ± 200 PPM (Used in AL,BL). Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 200 PPM (Used in AL). Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 200 PPM (Used in AL,BL). Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 200 PPM (Used in AL,BL). Ceramic: 6 pF ± 0.25 pF 500 VDCW, coef 0 ± 200 PPM (Used in AL,BL). Ceramic: 7 pF ± 0.55 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,BL). Ceramic: 7 pF ± 0.55 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,AH,BH). Ceramic: 7 pF ± 0.25 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,AH,BH). Ceramic: 7 pF ± 0.55 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,AH,BH). Ceramic: 7 pF ± 0.55 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,B,C,C,AH). Ceramic: 7 pF ± 0.55 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,B,C,C,AH). Ceramic: 6 pF ± 0.55 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,B,C,C,AH). Ceramic: 6 pF ± 0.55 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,B,C,C,AH). Ceramic: 4 pF ± 0.25 pF 500 VDCW, coef 0 ± 600 PPM (Used in AL,B,C,C,AH). Ceramic: 4 pF ± 0.25 pF 500 VDCW, coef 0 ± 6000 PPM (Used in AL,B,C,C,AH). Ceramic: 4 pF ± 0.25 pF 500 VDCW, coef 0 ± 60000000	, temp , temp
Ceramic: 3 pF ± 0.25 pF 500 VDCW coef 0 ± 120 PPM (Used in AH,BH). Ceramic: 4 pF ± 0.25 pF 500 VDCW, 0 ± 60 PPM (Used in AL,BL,CL, Ceramic: 5 pF ± 0.5 pF 500 VDCW, t 0 ± 60 PPM (Used in BH). Ceramic: 7 pF ± 0.5 pF 500 VDCW, t 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 7 pF ± 0.25 pF 500 VDCW 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 2 pF ± 0.25 pF 500 VDCW coef 0 ± 120 PPM (Used in AL,AH,B Ceramic: 2 pF ± 0.25 pF 500 VDCW, coef 0 ± 250 PPM (Used in BL,CL,CH Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 250 PPM (Used in CH). Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 250 PPM (Used in AH,BH,C Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 250 PPM (Used in AL). Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL). Ceramic: 4 pF ± 0.25 pF 500 VDCW coef 0 ± 60 PPM (Used in AL). Ceramic: 4 pF ± 0.25 pF 500 VDCW coef 0 ± 60 PPM (Used in AL). Ceramic: 4 pF ± 0.25 pF 500 VDCW coef 0 ± 60 PPM (Used in AL). Ceramic: 3 pF ± 0.25 pF 500 VDCW coef 0 ± 60 PPM (Used in AL). Ceramic: 3 pF ± 0.25 pF 500 VDCW coef 0 ± 60 PPM (Used in AL). Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,BL). Ceramic: 7 pF ± 0.5 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,BL). Ceramic: 7 pF ± 0.5 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,BL). Ceramic: 7 pF ± 0.5 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,AL,BH). Ceramic: 7 pF ± 0.5 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,AL,AH). Ceramic: 7 pF ± 0.5 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,AL,CL,AH). Ceramic: 7 pF ± 0.5 pF 500 VDCW, 0 ± 60 PPM (Used in BH,CL). Ceramic: 6 pF ± 0.5 pF 500 VDCW, 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ± 0.5 pF 500 VDCW, 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ± 0.5 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ± 0.5 pF 500 VDCW, coef 0 ± 0 PPM (Used in AL,BL,CL,CH). Ceramic: 4 pF ± 0.5 pF 500 VDCW, t 0 ± 60 PPM (Used in AL,BL,CL,CH). Ceramic: 4 pF ± 0.5 pF 500 VDCW, t 0 ± 60 PPM (Used in AL,BL,CL,CL)	, temp
coef 0±60 PPM (Used in AL,BL,CL, Ceramic: 6 pF ±0.5pF 500 VDCW, 0±60 PPM (Used in CH). Ceramic: 7 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 7 pF ±0.25 pF 500 VDCW coef 0±120 PPM (Used in AL,BL,CL,AH). Ceramic: 2 pF ±0.25 pF 500 VDCW coef 0±250 PPM (Used in AL,AH,B Ceramic: 2 pF ±0.25 pF 500 VDCW coef 0±250 PPM (Used in AL,AH,B Ceramic: 3 pF ±0.25 pF 500 VDCW coef 0±250 PPM (Used in AH,BH,C Ceramic: 3 pF ±0.25 pF 500 VDCW coef 0±120 PPM (Used in AL,AH,B Ceramic: 3 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL). Ceramic: 3 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL). Ceramic: 4 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL). Ceramic: 3 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL). Ceramic: 3 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,BL). Ceramic: 6 pF ±0.25 pF 500 VDCW, coef 0±60 PPM (Used in AL,BL). Ceramic: 7 pF ±0.5pF 500 VDCW, coef 0±60 PPM (Used in AL,BL). Ceramic: 2 pF ±0.25 pF 500 VDCW, coef 0±60 PPM (Used in AL,BL). Ceramic: 7 pF ±0.5pF 500 VDCW, coef 0±60 PPM (Used in AL,BL). Ceramic: 7 pF ±0.5pF 500 VDCW, coef 0±60 PPM (Used in AL,BL). Ceramic: 7 pF ±0.5p F 500 VDCW, coef 0±60 PPM (Used in AL,AH,BH) Ceramic: 7 pF ±0.5p F 500 VDCW, coef 0±60 PPM (Used in AL,AL,AH). Ceramic: 7 pF ±0.5p F 500 VDCW, coef 0±60 PPM (Used in AL,AL,CL,AH). Ceramic: 7 pF ±0.5p F 500 VDCW, 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ±0.5pF 500 VDCW, 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ±0.5pF 500 VDCW, 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, t 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 5	
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Ceramic: 5 pF ± 0.25 pF 500 VDCW, coef 0 \pm 60 PPM (Used in AL). Ceramic: 4 pF ± 0.25 pF 500 VDCW coef 0 \pm 60 PPM (Used in BL). Ceramic: 4 pF ± 0.25 pF 500 VDCW coef 0 \pm 60 PPM (Used in CH). Ceramic: 3 pF ± 0.25 pF 500 VDCW, coef 0 \pm 120 PPM (Used in AH,BH). Ceramic: 6 pF ± 0.25 pF 500 VDCW, coef 0 \pm 60 PPM (Used in AL,BL). Ceramic: 7 pF ± 0.5 pF 500 VDCW, to ± 60 PPM (Used in AL,BL). Ceramic: 2 pF ± 0.25 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,AH,BH) Ceramic: 1 pF ± 0.25 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,AH,BH) Ceramic: 1 pF ± 0.25 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,AH,BH) Ceramic: 7 pF ± 0.5 pF 500 VDCW, 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ± 0.5 pF 500 VDCW, 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ± 0.5 pF 500 VDCW, to ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ± 0.5 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ± 0.5 pF 500 VDCW, to ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ± 0.5 pF 500 VDCW, coef 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ± 0.5 pF 500 VDCW, to ± 0.5 PF 500 VDCW, coef 0 ± 60 PPM (Used in AL,BL,CL,AH). Ceramic: 3 pF ± 0.5 pF 500 VDCW, to ± 0.5 PF ± 0.5 PF 500 VDCW, to ± 0.5 PF \pm	, temp L).
coef 0 \pm 60 PPM (Used in BL). Ceramic: 4 pF \pm 0.25 pF 500 VDCW coef 0 \pm 60 PPM (Used in CH). Ceramic: 3 pF \pm 0.25 pF 500 VDCW coef 0 \pm 120 PPM (Used in AH,BH). Ceramic: 6 pF \pm 0.25 pF 500 VDCW, coef 0 \pm 60 PPM (Used in AL,BL). Ceramic: 7 pF \pm 0.5 pF 500 VDCW, t 0 \pm 60 PPM (Used in CL). Ceramic: 2 pF \pm 0.25 pF 500 VDCW, coef 0 \pm 60 PPM (Used in AL,AH,BH) Ceramic: 1 pF \pm 0.25 pF 500 VDCW coef 0 \pm 60 PPM (Used in AL,AH,BH) Ceramic: 7 pF \pm 0.5 pF 500 VDCW, 0 \pm 60 PPM (Used in AL,A,AH,BH) Ceramic: 6 pF \pm 0.5 pF 500 VDCW, 0 \pm 60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF \pm 0.5 pF 500 VDCW, t 0 \pm 60 PPM (Used in BH,CH).	
Ceramic: 4 pF ± 0.25 pF 500 VDCW coef 0 \pm 60 PPM (Used in CH). Ceramic: 3 pF ± 0.25 pF 500 VDCW coef 0 \pm 120 PPM (Used in AH,BH). Ceramic: 6 pF ± 0.25 pF 500 VDCW, coef 0 \pm 60 PPM (Used in AL,BL). Ceramic: 7 pF ± 0.5 pF 500 VDCW, t 0 \pm 60 PPM (Used in CL). Ceramic: 2 pF ± 0.25 pF 500 VDCW coef 0 \pm 60 PPM (Used in AL,AH,BH) Ceramic: 1 pF ± 0.25 pF 500 VDCW coef 0 \pm 60 PPM (Used in AL,AH,BH) Ceramic: 7 pF ± 0.5 pF 500 VDCW, 0 \pm 60 PPM (Used in AL,A,AH,BH) Ceramic: 7 pF ± 0.5 pF 500 VDCW, 0 \pm 60 PPM (Used in AL,A,CL,CH) Ceramic: 6 pF ± 0.5 pF 500 VDCW, t 0 \pm 60 PPM (Used in BH,CL), Ceramic: 4 pF ± 0.25 pF 500 VDCW, coef 0 \pm 60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ± 0.25 pF 500 VDCW, coef 0 \pm 60 PPM (Used in AL,BL,CL,AH).	, temp
coef 0±120 PPM (Used in AH,BH). Ceramic: 6 pF ±0.25pF 500 VDCW, coef 0±60 PPM (Used in AL,BL). Ceramic: 7 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in CL). Ceramic: 2 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,AH,BH Ceramic: 1 pF ±0.25 pF 500 VDCW, coef 0±60 PPM (Used in BL,CL,CH Ceramic: 7 pF ±0.5 pF 500 VDCW, 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ±0.5pF 500 VDCW, 0±60 PPM (Used in BH,CH). Ceramic: 4 pF ±0.25 pF 500 VDCW, coef 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 4 pF ±0.25 pF 500 VDCW, coef 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 3 pF ±0.25pF 500 VDCW,	, temp
coef 0±60 PPM (Used in AL,BL). Ceramic: 7 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in CL). Ceramic: 2 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,AH,BH Ceramic: 1 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in BL,CL,CH Ceramic: 7 pF ±0.5 pF 500 VDCW, 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in BH,CH). Ceramic: 4 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 3 pF ±0.25 pF 500 VDCW	, temp
0±60 PPM (Used in CL). Ceramic: 2 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,AH,BH Ceramic: 1 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in BL,CL,CH Ceramic: 7 pF ±0.5 pF 500 VDCW, 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in BH,CH). Ceramic: 4 pF ±0.25 pF 500 VDCW, coef 0±60 PPM (Used in AL,BL,CL, Ceramic: 3 pF ±0.25 pF 500 VDCW,	temp
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coef 0±60 PPM (Used in BL,CL,CH Ceramic: 7 pF ±0.5 pF 500 VDCW, 0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in BH,CH). Ceramic: 4 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,BL,CL, Ceramic: 3 pF ±0.25pF 500 VDCW,	, temp).
0±60 PPM (Used in AL,BL,CL,AH). Ceramic: 6 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in BH,CH). Ceramic: 4 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,BL,CL, Ceramic: 3 pF ±0.25pF 500 VDCW,	, temp).
0±60 PPM (Used in BH,CH). Ceramic: 4 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,BL,CL, Ceramic: 3 pF ±0.25pF 500 VDCW,	temp coef
coef 0±60 PPM (Used in AL,BL,CL, Ceramic: 3 pF ±0.25pF 500 VDCW,	emp coef
Ceramic: 3 pF ±0.25pF 500 VDCW,	
	temp
Mica: 2 pF \pm 0.25pF 500 VDCW (Us Mica: 1.5 pF \pm 0.25pF 500 VDCW (U	,
CH). Ceramic: 5 pF ±0.25pF 500 VDCW,	
coef 0 ± 60 PPM (Used in AL). Ceramic: 4 pF ±0.25 pF 500 VDCW	-
coef 0 ± 60 PPM (Used in BL). Ceramic: 3 pF ± 0.25 pF 500 VDCW,	, I
coef 0±120 PPM (Used in CL). Mica: 3 pF ±0.25pF 500 VDCW (Us	
Ceramic: 6 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in AH,BH).	<i>'</i>
Ceramic: 5 pF ±0.5pF 500 VDCW, t 0±60 PPM (Used in AL).	emp coef
Ceramic: 4 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in BH).	, temp
Ceramic: 4 pF ±0.25 pF 500 VDCW coef 0±60 PPM (Used in AL,BL,BH)	
Ceramic: 7 pF ±0.5 pF 500 VDCW, 0±60 PPM (Used in BH).	· ·
Ceramic: 3 pF ±0.25pF 500 VDCW, coef 0±120 PPM (Used in CL).	temp coef

(Continued)

SYMBOL	PART NO.	DESCRIPTION
C66		Ceramic: 5 pF \pm 0.25pF 500 VDCW, temp coef 0 \pm 60 PPM (Used in CH).
C67		Ceramic: 2 pF ±0.25 pF 50 VDCW, temp coef 0±30 PPM (Used in AH,BH,CH).
C68		Ceramic: 100 pF \pm 5% 50 VDCW, temp coef $0\pm$ 30 PPM.
C69		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM (Used in AH,BH,CH).
C71		Tantalum: 10 μ F ±20%,35 VDCW (Used in AH,BH,CH).
C71		Tantalum: 10 μ F ±20% 16 VDCW (Used in AL,BL,CL).
C72		Electrolytic: 10 μ F ±10%.
C73		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60 PPM (Used in AH,BH,CH).
C82		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM.
C84 thru C88		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM.
C89		Ceramic: 0.1 μ F \pm 5% 25 VDCW. (Used in AL,AH,BH,CH).
C89		Ceramic: 0.022 μ F ±5% 25 VDCW. (Used in BL,CL).
C90		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM (Used in AH,BH,CH).
C91		Tantalum: 4.7 μF ±10% 16 VDCW. (Used in AL,AH,BH).
C91		Tantalum: 3.3 μ F ±10% 16 VDCW. (Used in BL).
C91		Tantalum: 1.0 μ F ±10% 16 VDCW. (Used in CL,CH).
C92		Electrolytic: 100 µF ±20% 50 VDCW,
C93		Mica: 100 pF ±5% 500 VDCW,
C95		Electrolytic: 33 μ F ±10% 25 VDCW,
C96		Ceramic: 18 pF \pm 5% 500 VDCW, temp coef 0 \pm 60 PPM (Used in AH).
C96		Ceramic: 15 pF \pm 5% 500 VDCW, temp coef 0 \pm 60 PPM (Used in BH,CH).
C97		Mica: 24 pF ±5% 100 VDCW (Used in CH).
C98		Mica: 90 pF ±5% 500 VDCW (Used in AH,BH,CH).
C99		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM (Used in AL,BL,CL).
C99		Ceramic: 0.022 μF ±5% 50 VDCW, temp coef 0±30 PPM (Used in AH).
C151		Ceramic: 330 pF ±5% 50 VDCW. (Used in AL, CL, AH, BH).
C151		Ceramic: 7 pF ±0.5% 50 VDCW, temp coef 0±30 PPM (Used in BL).
		DIODES
CD1		Silicon: fwd current 3A, 200 PIV; sim to MOTOROLA MR751 (Used in AH,BH,CH).
CD2		Ceramic: Varistor; sim to HOKURIKU 22ZR- 10D.
CD3 and CD4		Diode: sim to PANASONIC MA741-TX.
0.0.5		

Diode M1809-TIL. (Used in AL,BL,CL).

Diode M1809-TIL. (Used in AH,BH,CH).

Silicon: fast recovery (2 diodes in cathode common); sim to TOSHIBA 1SS184 TE85L.

Diode (Used in AH,BH,CH).

Diode M1809-TIL.

Diode M1809-TIL.

CD5

CD6

CD7

CD8

CD9

CD10

			SYMBOL	PART NO.	DESCRIPTION
SYMBOL	PART NO.	DESCRIPTION	P2		Coaxial cable with connector (Used in AL,BL,CL).
CD11 and CD12		Silicon: fast recovery, (RF Switch); sim to MITSUBISHI MI301	P2		Coaxial cable with connector (Used in AH,BH,CH).
		INTEGRATED CIRCUITS			RESISTORS
HC1		RF Power Amplifier: sim to MITSUBISHI M57704M-38 (Used in AL,AH).	R1		Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
HC1		RF Power Amplifier: sim to MITSUBISHI M57704H-38 (Used in BL,BH).	R2 and		Metal film: 22 ohms ±5%, 100 VDCW, 1/10W.
HC1		RF Power Amplifier: sim to MITSUBISHI M57704SH-38 (Used in CL,CH).	R3 R4		Metal film: 470 ohms ±5%, 100 VDCW,
IC1		Linear: Positive Voltage Regulator; sim to PANASONIC AN6541.	R5		1/10W. Metal film: 24 ohms ±5%, 350 VDCW, 3W
IC2		Linear, Dual OP Amp: sim to NEW JRC NJM3404AM.	R6		(Used in AH,BH,CH). Metal film: 3.3K ohms ±5%, 250 VDCW,
J3		Connector.	and R7		1W (Used in AH,BH,CH).
J4		Connector.	R8		Metal film: 24 ohms ±1%, 500 VDCW,
		INDUCTORS	NO		1.5W (Used in AH,BH,CH).
L1 L2		Coil. Coil (Used in AL,AH,BH).	R10		Metal film: 82 ohms \pm 5%, 100 VDCW, 1/8W (Used in AH,BH,CH).
L2 L3		Coil (Used in BL,CL,CH). Coil.	R10		Metal film: 68 ohms \pm 5%, 100 VDCW, 1/10W (Used in AL,BL,CL).
L3 L4		Coil.	R11		Metal film: 120 ohms ±5%, 200 VDCW, 1/8W (Used in AH,BH,CH).
L5 L5		Coil. (Used in AL,BL,CL). Coil. (Used in AH,BH,CH).	R11		Metal film: 82 ohms ±5%, 100 VDCW, 1/8W (Used in AL,BL,CL).
L6 L6		Coil (Used in AH,BH,CH). Coil (Used in AL).	R12		Metal film: 120 ohms \pm 5%, 200 VDCW, 1/8W (Used in AH,CH).
L6		Coil (Used in BL,CL).	R12		Metal film: 82 ohms \pm 5%, 200 VDCW, 1/8W (Used in BH).
L7		Coil (Used in AH,BH,CH).	R12		Metal film: 100 ohms ±5%, 200 VDCW,
L8		Coil (Used in AH,BH,CH).	and R13		1/8W (Used in AL,BL,CL).
L9 L10		Coil (Used in AH,BH,CH). Coil (Used in AH,BH,CH).	R13		Metal film: 82 ohms ±5%, 100 VDCW, 1/10W (Used in AH,BH,CH).
L11 L12		Coil (Used in AH,BH,CH). Coil (Used in AH,BH,CH).	R14		Metal film: 12k ohms ±5%, 100 VDCW, 1/10W (Used in AH).
L13		Coil (Used in AH,BH,CH).	R14		Metal film: 18k ohms ±5%, 100 VDCW, 1/10W (Used in BH).
L14 L15		Coil (Used in AH,BH,CH). Coil (Used in AH,BH).	R14		Metal film: 47k ohms ±5%, 100 VDCW, 1/10W (Used in CH).
L15 L16		Coil (Used in CH). Coil (Used in AL,BL,CL).	R14		Metal film: 2.7 ohms ±5%, 100 VDCW, 1/10W (Used in AL,BL,CL).
L16		Coil (Used in AH,BH,CH).	R15		Metal film: 100 ohms ±5%, 100 VDCW, 1/10W.
L17 L18		Coil. Coil.	R16		Metal film: 1.5k ohms ±5%, 100 VDCW, 1/10W (Used in AH).
L19 L19		Coil (Used in AH,BH,CH). Coil (Used in AL,BL,CL).	R16		Metal film: 3.9K ohms ±5%, 100 VDCW, 1/10W (Used in BH).
L20 and		Coil.	R16		Metal film: 4.7K ohms ±5%, 100 VDCW, 1/10W (Used in CH).
L21 L22		Coil.	R16		Metal film: 1K ohms ±5%, 100 VDCW, 1/10W (Used in AL,BL,CL).
L22 L23 and L24		Coil (Used in AH,BH).	R17 and R18		Metal film: 120 ohms ±5%, 250 VDCW, 1W (Used in AH,BH,CH).
L23 and L24		Coil (Used in CH).	R17 and R18		Metal film: 180 ohms ±5%, 250 VDCW, 1W (Used in AL,BL,CL).
L23		Coil (Used in AL,BL,CL,).	R19		Metal film: 47K ohms ±5%, 200 VDCW, 1/4W.
L24 L25		Coil (Used in AL,BL,CL,). Coil (Used in AH,BH,CH).	R20		Metal film: 4.7K ohms \pm 5%, 100 VDCW, 1/10W.
P1		Coaxial cable with connector (Used in AL,BL,CL).	R21		Metal film: 680 ohms ±5%, 200 VDCW, 1/4W.
P1		Coaxial cable with connector (Used in AH,BH,CH).	R35		Metal film: 10K ohms \pm 5%, 100 VDCW, 1/10W.

PARTS LIST

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LBI-39034C

SYMBOL	PART NO.	DESCRIPTION
R36		Metal film: 3.3K ohms ±5%, 100 VDCW,
R36		1/10W (Used in AH). Metal film: 1.8K ohms ±5%, 100 VDCW, 1/10W (Used in BH,CH).
R36		Metal film: 2.2K ohms ±5%, 100 VDCW, 1/10W. (Used in AL,BL,CL).
R37		Metal film: 1.8K ohms ±5%, 100 VDCW, 1/10W (Used in AL,AH).
R37		Metal film: 2.2K ohms ±5%, 100 VDCW, 1/10W (Used in BH).
R37		Metal film: 1.5K ohms ±5%, 100 VDCW, 1/10W (Used in BL).
R37		Metal film: 1.2K ohms ±5%, 100 VDCW, 1/10W (Used in CL,CH).
R38		Metal film: 10K ohms ±5%, 100 VDCW, 1/10W, (Used in BH).
R39		Metal film: 2.2K ohms ±5%, 100 VDCW, 1/10W (Used in CH).
R40		Metal film: 27K ohms ±5%, 100 VDCW, 1/10W.
R41		Metal film: 2.2K ohms ±5%, 100 VDCW, 1/10W.
R42		Metal film: 68K ohms ±5%, 100 VDCW, 1/10W (Used in AL,AH).
R42		Metal film: 150K ohms \pm 5%, 100 VDCW, 1/10W (Used in BL).
R42		Metal film: 56K ohms \pm 5%, 100 VDCW, 1/10W (Used in CL).
R42		Metal film: 82K ohms \pm 5%, 100 VDCW, 1/10W (Used in BH).
R42		Metal film: 12K ohms \pm 5%, 100 VDCW, 1/10W (Used in CH).
R43		Metal film: 1K ohms ±5%, 100 VDCW, 1/10W.
R44 and R45		Metal film: 820 ohms ±5%, 100 VDCW, 1/10W.
R46 and R47		Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
R48		Metal film: 10 ohms ±5%, 200 VDCW, 1/8W.
R49		Polyester: sim to MURATA PTH9M04BE222TS2F333.
R50		Metal film: 100K ohms ±5%, 100 VDCW, 1/10W.
R52		Metal film: 50 ohms, 10W (Used in AL, BL, CL, AH, BH).
RV1		Variable. TRANSISTOR
TR1		Silicon,NPN: sim to MITSUBISHI 2SC3102.
TR2		Silicon, NPN: sim to MITSUBISHI 2SC4989
and TR3		(Used in AH,BH,CH).
TR4		Silicon, PNP: sim to NEC 2SB624-T1B BV3.
TR5 and TR6		Silicon, PNP: sim to NEC 2SB596-T1B DV3.
TR7		Silicon PNP: sim to PANASONIC 2SB953A.
TR8		Silicon NPN: sim to PANASONIC 2SD1271-Q.
		WIRE
W1		Jumper wire: (Used in AH,BH,CH).
W3		Jumper wire: (Used in AH,BH,CH).

PRODUCTION CHANGES

Changes in the equipment to improve or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number on the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for the description of parts affected by these revisions.

REV. A - Power Amplifier Units 344A4573P1 & P2

To improve stability. Deleted capacitor C6. Changed capacitor C45 to 4.7 $\mu\text{F}.$

REV. A - Power Amplifier Units 344A4573P3, P4 & P5

To improve stability. Changed capacitor C12 from 36 pF to 47 pF metal mica. This improves matching to the final amplifier.

REV. B- Power Amplifier Units 344A4573P3, P4 & P5

To improve PA stability. Added RC feedback to power amplifier transistor TR1 consisting of a 50-ohm resistor and a 330 pF capacitor.

REV. A - Power Amplifier Units 344A4573P6 & P7

To improve PA stability. Added RC feedback to power amplifier transistor TR1 consisting of a 50-ohm resistor and a 330 pF capacitor.

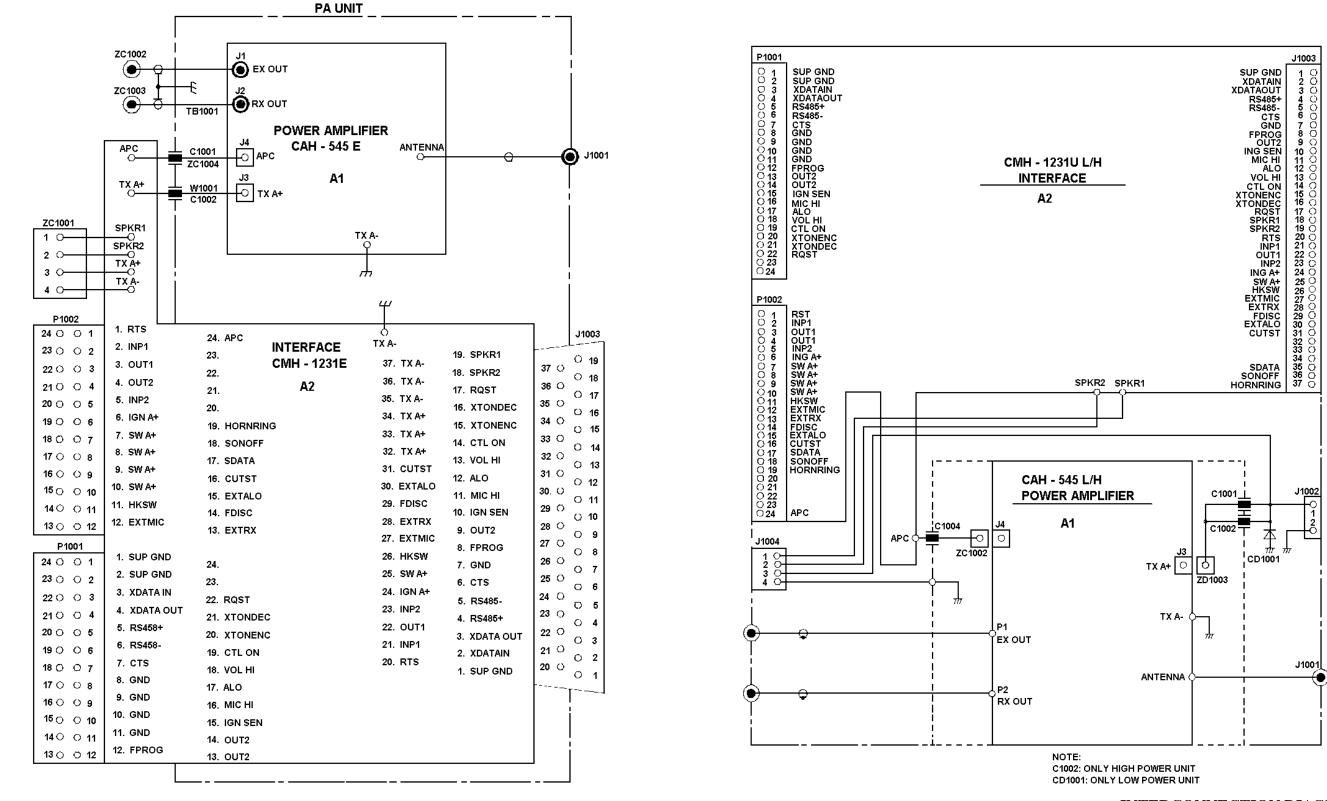
REV. B - Power Amplifier Units 344A4573P1 & P2

For improved ETSI radiated spurs ground clips added.

REV. A - Power Amplifier Units 344A4573P8

Incorporated in first production units.

INTERCONNECTION DIAGRAM



INTERCONNECTION DIAGRAM EUROPEAN UHF PA UNIT

(DD00-JHM-471PE)

LBI-39034C

INTERCONNECTION DIAGRAM U.S.A. UHF PA UNIT

(DD00-JHM-471PL/H)

COMPONENT IDENTIFICATION CHART 403-512 MHz 35/40-Watt Power Amplifier

PART	CAH-545AL 403-440 MHz (40W)	CAH-545BL 440-470 MHz (40W)	CAH-545CL 470-512 MHz (35W)
C7	12 pF	12 pF	8 pF (8-10)
C9	56 pF	47 pF	47 pF
C10	56 pF	47 pF	36 pF
C11	36 pF	33 pF	33 pF
C12	51 pF (47-56)	47 pF (47-56)	47 pF (39-56)
C13	30 pF	27 pF	24 pF
C41	12 pF	10 pF (8-12)	10 pF
C50	6 pF	6 pF	5 pF
C58	3 pF	2 pF	2 pF
C59	5 pF	4 pF	3 pF
C60	6 pF	6 pF	7 pF
C61	2 pF	1 pF	1 pF
C64	5 pF	4 pF	3 pF
C65	5 pF	4 pF	4 pF
C66	4 pF	4 pF	3 pF
C89	0.1 μF	0.022 µF	0.022 µF
C91	4.7 μF	3.3 µF	1.0 µF
C151	330 pF	7 pF	330 pF
R37	1.8kΩ	1.5kΩ	1.2kΩ
R42	$47 \mathrm{k}\Omega$	150kΩ	56k Ω
L2	6LALD20855	6LALD20850	6LALD20850
L6	6LALD20855	6LALD20850	6LALD20850
HC1	M57704M-38	M57704H-38	M57704SH-38

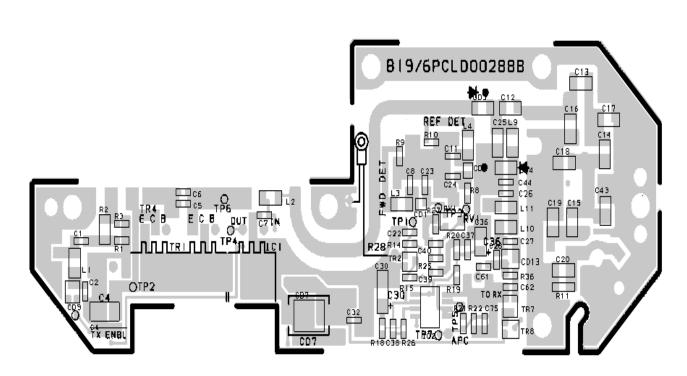
(MADE FROM DD02-CAH-545L 2/2)

PART	CAH-545AH 403-440 MHz (100W)	CAH-545BH 440-512 MHz (100W)	CAH-545CH 470-512 MHz (80W)
C7	12 pF	10 pF	10 pF
C9	56 pF	47 pF	47 pF
C10	56 pF	43 pF	36 pF
C11	56 pF	56 pF	33 pF
C12	39 pF	33 pF	33 pF
C12 C13	30 pF	24 pF	55 pr
			- 4 - E
C15	3 pF	5 pF	4 pF
<u>C18</u>	10 pF	9 pF	8 pF
<u>C20</u>	56 pF	47 pF	36 pF
C21	47 pF	39 pF	36 pF
C22	39 pF	36 pF	33 pF
C23	56 pF	47 pF	47 pF
C24	30 pF	24 pF	18 pF
C26	10 pF	10 pF	8 pF
C27	10 pF	9 pF	8 pF
C29	47 pF	39 pF	36 pF
C30	56 pF	47 pF	36 pF
C31	56 pF	47 pF	47 pF
C31 C32	39 pF	36 pF	33 pF
		24 pF	35 pr 18 pF
C33	30 pF		
C35	10 pF	10 pF	8 pF
<u>C41</u>	8 pF	8 pF	6 pF
C44	6 pF	5 pF	5 pF
C45	6 pF	5 pF	5 pF
C49	8 pF	7 pF	2 pF
C50	-	-	4 pF
C56	3 pF	3 pF	4 pF
C57	7 pF	5 pF	6 pF
C58	3 pF	3 pF	$2 \mathrm{pF}$
C59	3 pF	3 pF	2 pF
C60	3 pF	3 pF	4 pF
C61	2 pF	2 pF	1 pF
C62	7 pF	6 pF	6 pF
C63	4 pF	4 pF	3 pF
			1.5 pF
<u>C64</u>	3 pF	2 pF	
<u>C65</u>	6 pF	4 pF	4 pF
<u>C66</u>	-	4 pF	5 pF
C91	4.7 μF	<u>4.7 μF</u>	1.0 μF
C96	18 pF	15 pF	15 pF
<u>C97</u>	-	-	24 pF
C99	0.022 µF	-	-
R12	120Ω	82Ω	120Ω
R14	$12k\Omega$	18kΩ	47kΩ
R16	1.5kΩ	3.9kΩ	4.7kΩ
R36	$3.3k\Omega$	$1.8 \mathrm{k}\Omega$	1.8kΩ
R37	1.8kΩ	$2.2k\Omega$	1.2kΩ
R38	-	$10k\Omega$	-
R39	2.7kΩ	2.7kΩ	2.2kΩ
R42	$68k\Omega$	$\frac{2.7 \text{KS2}}{82 \text{k}\Omega}$	$12k\Omega$
R53	UOK22	02832	12 k Ω
	-	-	
L2	6LALD20855	6LALD20855	6LALD20850
L15	6LALD20875	6LALD20875	6LALD20855
L23	6LALD12014	6LALD12014	6LALD12213
L24	6LALD12014	6LALD12014	6LALD12213
HC1	M57704M-38	M57704H-38	M57704SH-38

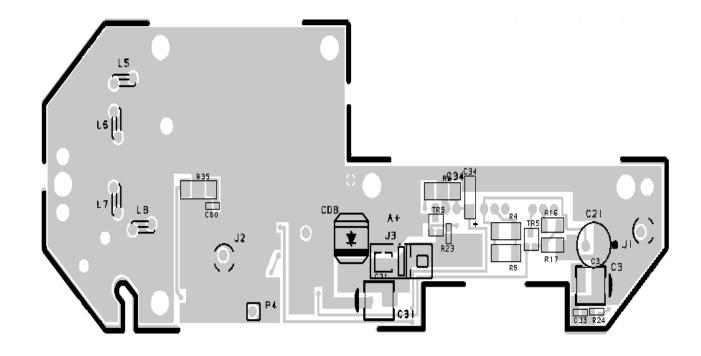
COMPONENT IDENTIFICATION CHART

403-512 MHz 80/100-Watt Power Amplifier

(MADE FROM DD03-CAH-545H 2/2)

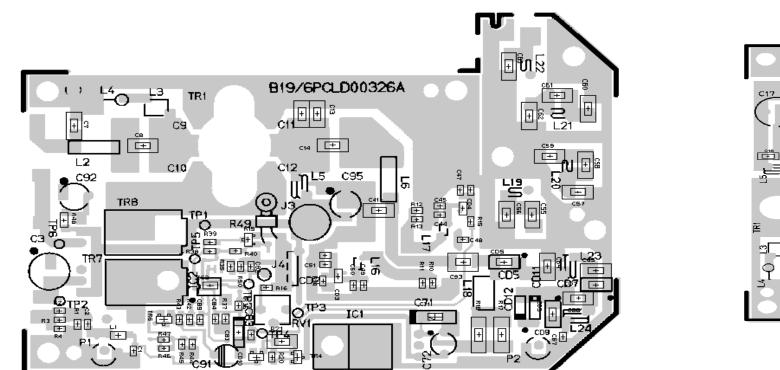


(B19/6PCLD00288B, Component Side Layout (B19/6PCLD00288B, Chip Components) (B19/6PClD00288B, Component Side)

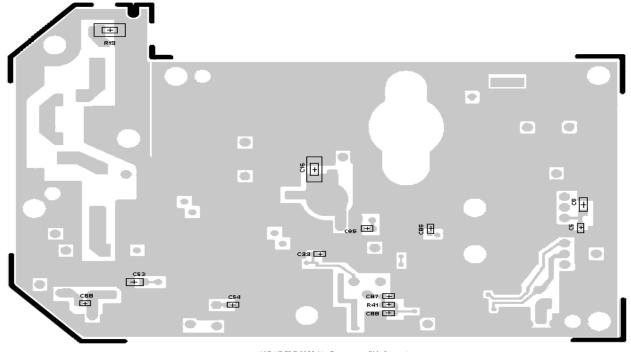


20-Watt Power Amplifier CAH-545E

(B19/6PCLD00288B, Chip Components) (B19/6PCLD00288B, Solder Side

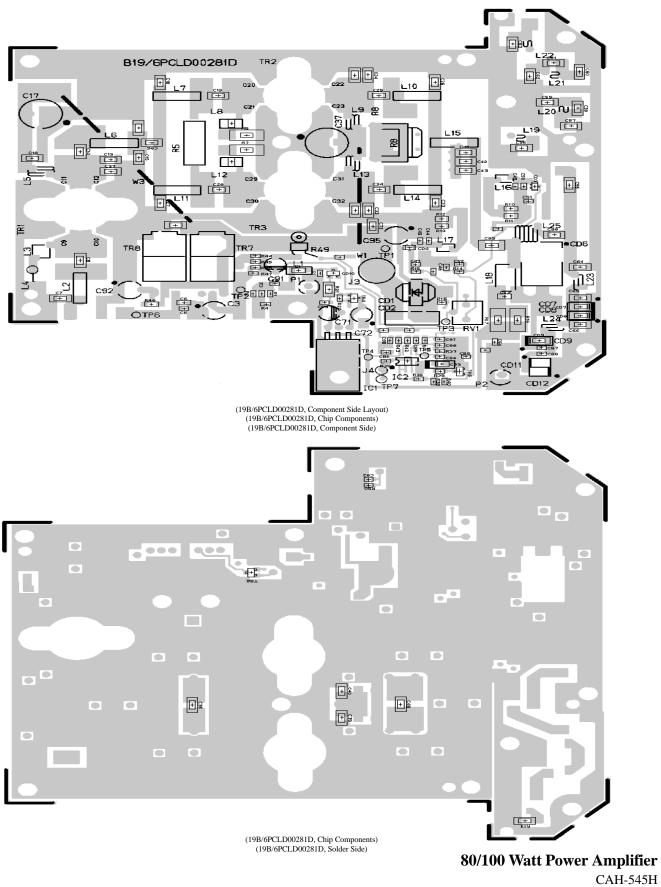


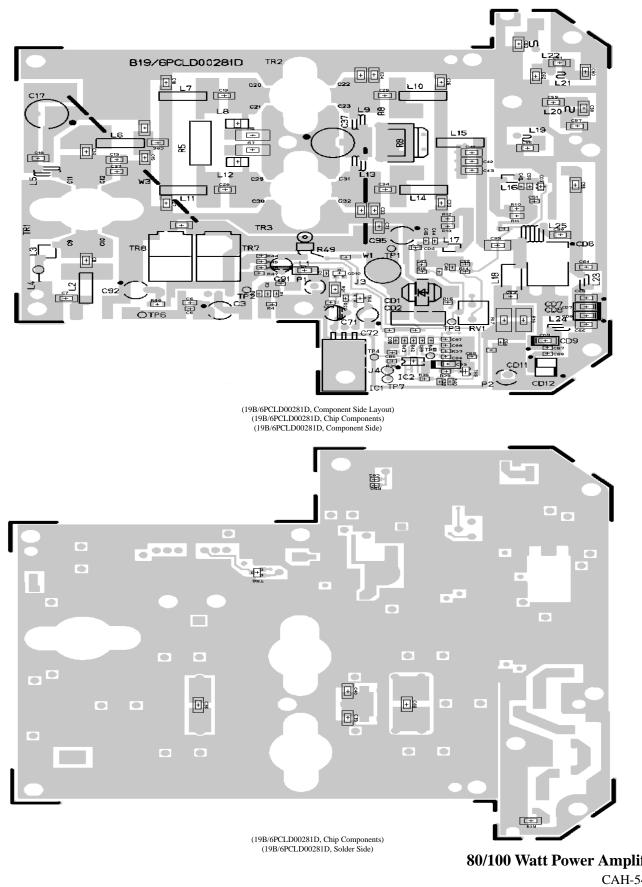
⁽¹⁹B/6PCLD00326A, Component Side Layout) (19B6PClD00326A, Chip Components) (19B6PLCD00326A, Component Side)



(19B/6PCLD00326A, Component Side Layout) (19B/6PCLD0032A, Chip Components) (19B/6PCLD00326A, Solder Side)

OUTLINE DIAGRAM

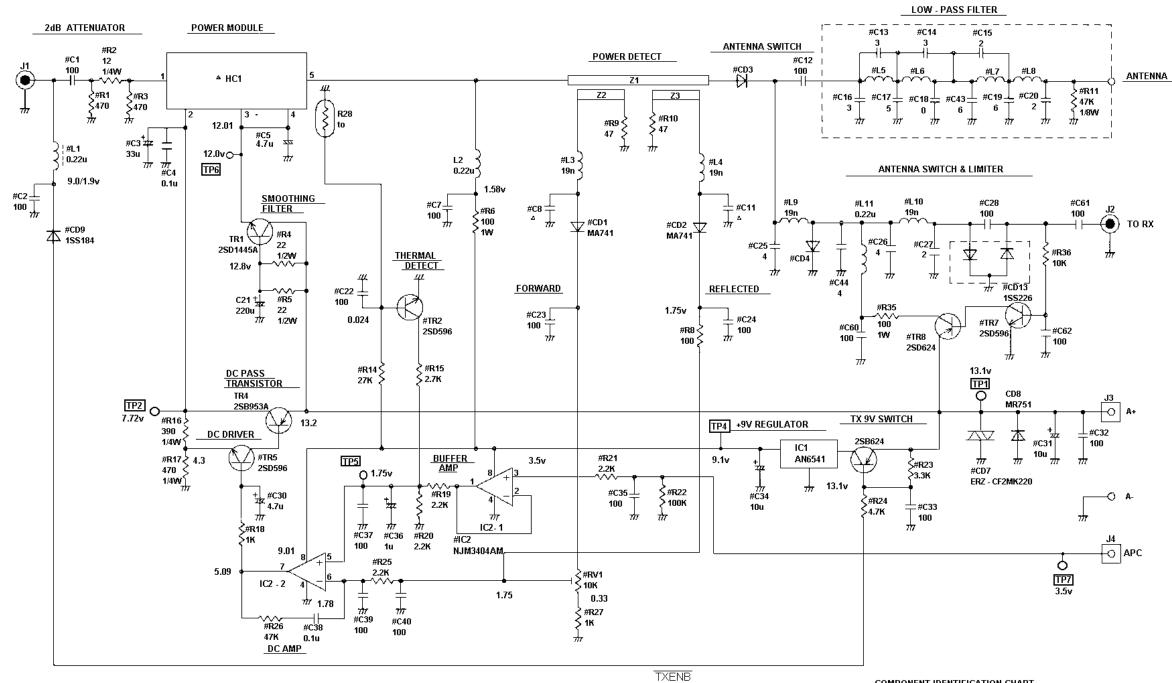




35/40 Watt Power Amplifier CAH-545L

LBI-39034C

SCHEMATIC DIAGRAM



NOTES:

1. "#" IDENTIFIES CHIP COMPONENTS

(EXAMPLE #R12 OR R12#) WHICH ARE LOCATED ON THE COMPONENT SIDE OF THE BOARD.

2. Z1, Z2 AND Z3 ARE STRIPLINE PART OF PWB. 3. RV1 IS FACTORY TUNED AND DOES NOT REQUIRE FURTHER ADJUSTMENT.

ALL RESISTORS ARE 1/10 OR 1/8 WATT UNLESS OTHERWISE SPECIFIED. RESISTOR VALUES IN $\ensuremath{\Omega}$ UNLESS FOLLOWED BY MULTIPLIER K OR M. CAPACITOR VALUES IN P UNLESS FOLLOWED BY MULTIPLIER $\mu_{\rm c}$ INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER m OR $\mu.$ DC VOLTAGE READINGS

ALL VOLTAGES ARE TYPICAL. VOLTAGES ARE MEASURED WITH A 10Meg OHM PER VOLT METER. REFERENCE TO GROUND. VOLTAGE READINGS ARE TAKEN WITH THE TRANSMITTER UNKEYED/KEYED. EX .45 (UNKEYED)/ .05 (KEYED).

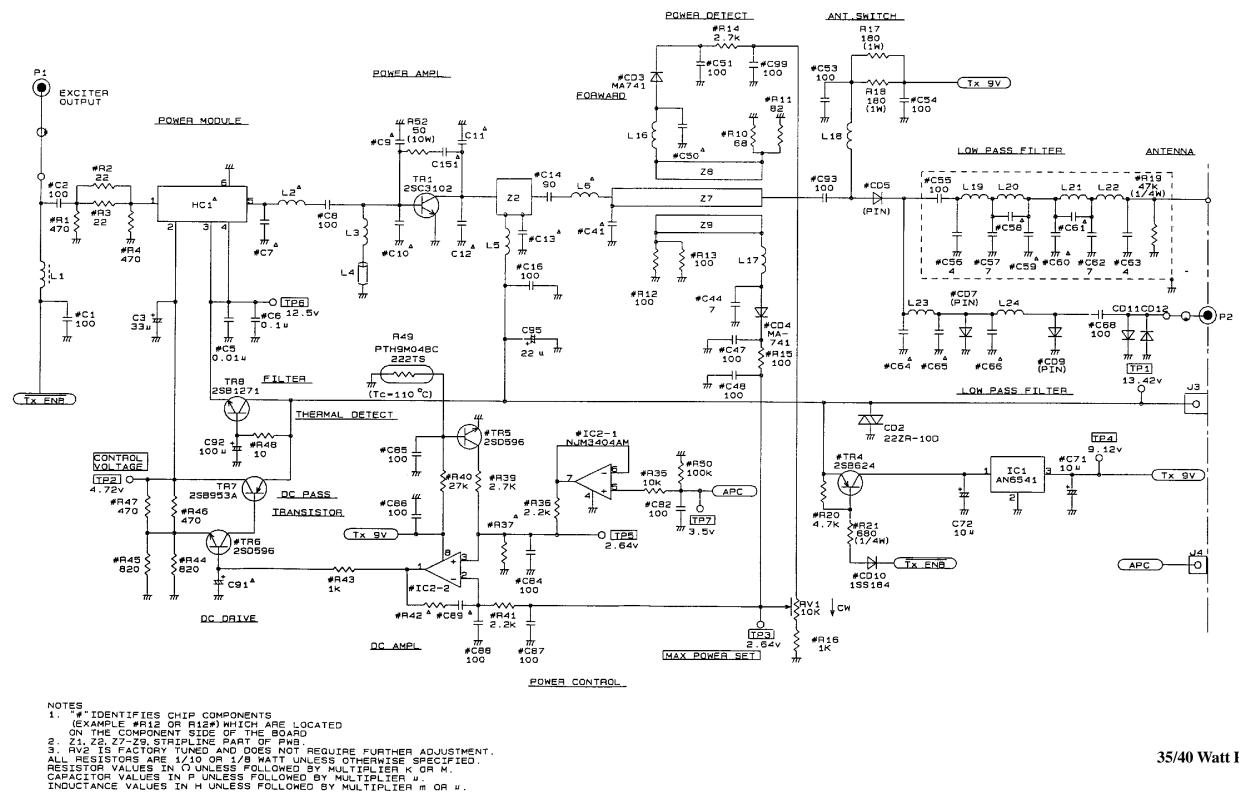
COMPONENT IDENTIFICATION CHART

PART	378-403 (мнz)	403-440 (MHz)	440 - 470 (MHz)
C8	6PF	7pF	брF
C11	6PF	7øF	6pF
HC1	M57729ULF-38	M57780L-38	M57788H-38

20 Watt Power Amplifier

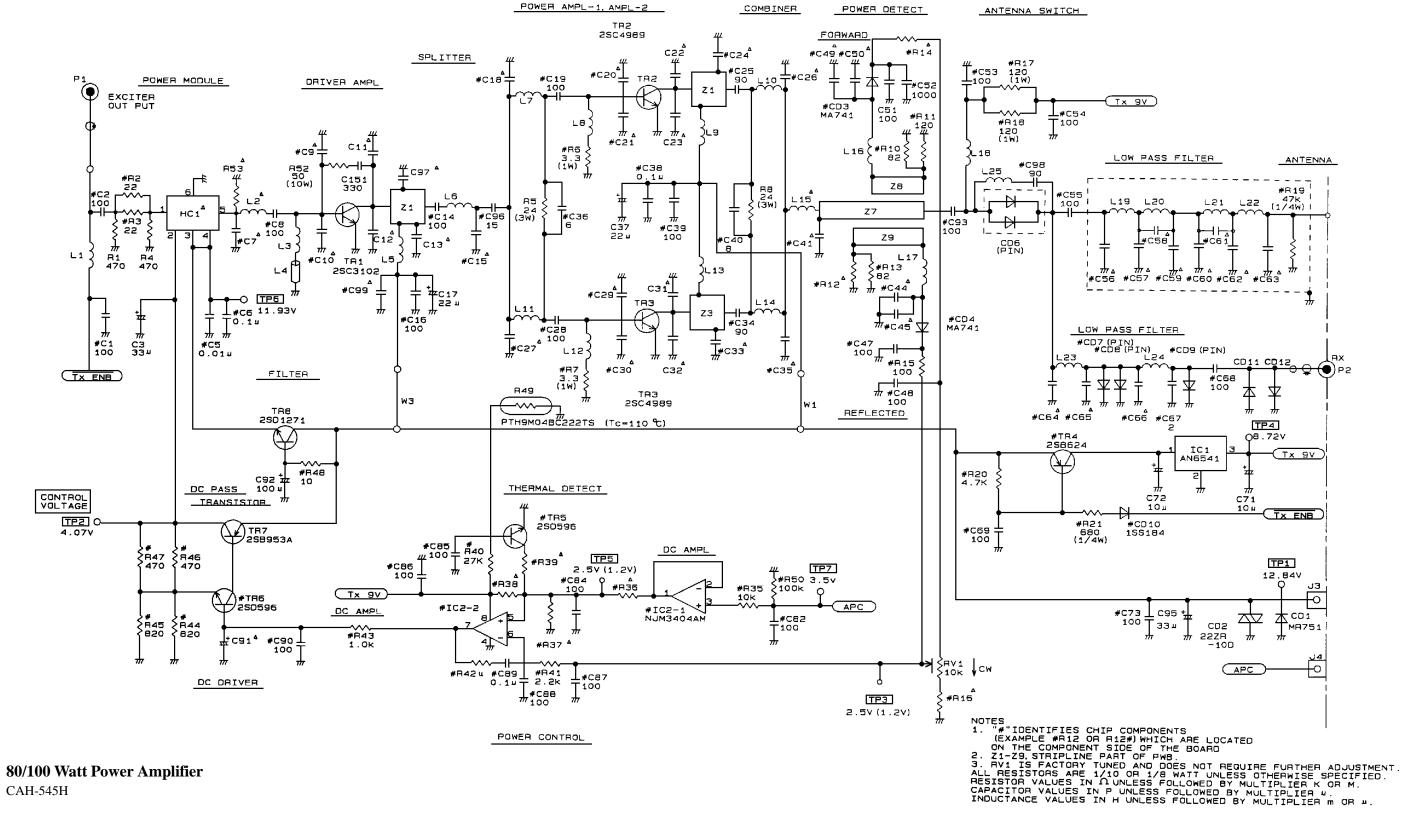
CAH-545E

(DD02-CAH-545E)



35/40 Watt Power Amplifier CAH-545L

(DD02-CAH-545L 1/2)



(DD03-CAH-545H 1/2)

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LBI-39034C